

# PBSS5230QA

30 V, 2 A PNP low V<sub>CEsat</sub> (BISS) transistor

23 August 2013

Product data sheet

## 1. General description

PNP low V<sub>CEsat</sub> Breakthrough In Small Signal (BISS) transistor in a leadless ultra small DFN1010D-3 (SOT1215) Surface-Mounted Device (SMD) plastic package with visible and solderable side pads.

NPN complement: PBSS4230QA.

## 2. Features and benefits

- Very low collector-emitter saturation voltage V<sub>CEsat</sub>
- High collector current capability I<sub>C</sub> and I<sub>CM</sub>
- High collector current gain h<sub>FE</sub> at high I<sub>C</sub>
- High energy efficiency due to less heat generation
- Reduced Printed-Circuit Board (PCB) area requirements
- Solderable side pads
- AEC-Q101 qualified

## 3. Applications

- Loadswitch
- Battery-driven devices
- Power management
- Charging circuits
- Power switches (e.g. motors, fans)

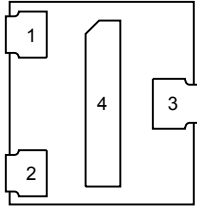
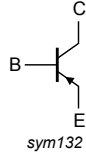
## 4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
V <sub>CEO</sub>	collector-emitter voltage	open base	-	-	-30	V
I <sub>C</sub>	collector current		-	-	-2	A
I <sub>CM</sub>	peak collector current	t <sub>p</sub> ≤ 1 ms; pulsed	-	-	-3	A
R <sub>CEsat</sub>	collector-emitter saturation resistance	I <sub>C</sub> = -1 A; I <sub>B</sub> = -100 mA; pulsed; t <sub>p</sub> ≤ 300 μs; δ ≤ 0.02; T <sub>amb</sub> = 25 °C	-	120	180	mΩ

## 5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	B	base	 <p>Transparent top view DFN1010D-3 (SOT1215)</p>	 <p>sym132</p>
2	E	emitter		
3	C	collector		
4	C	collector		

## 6. Ordering information

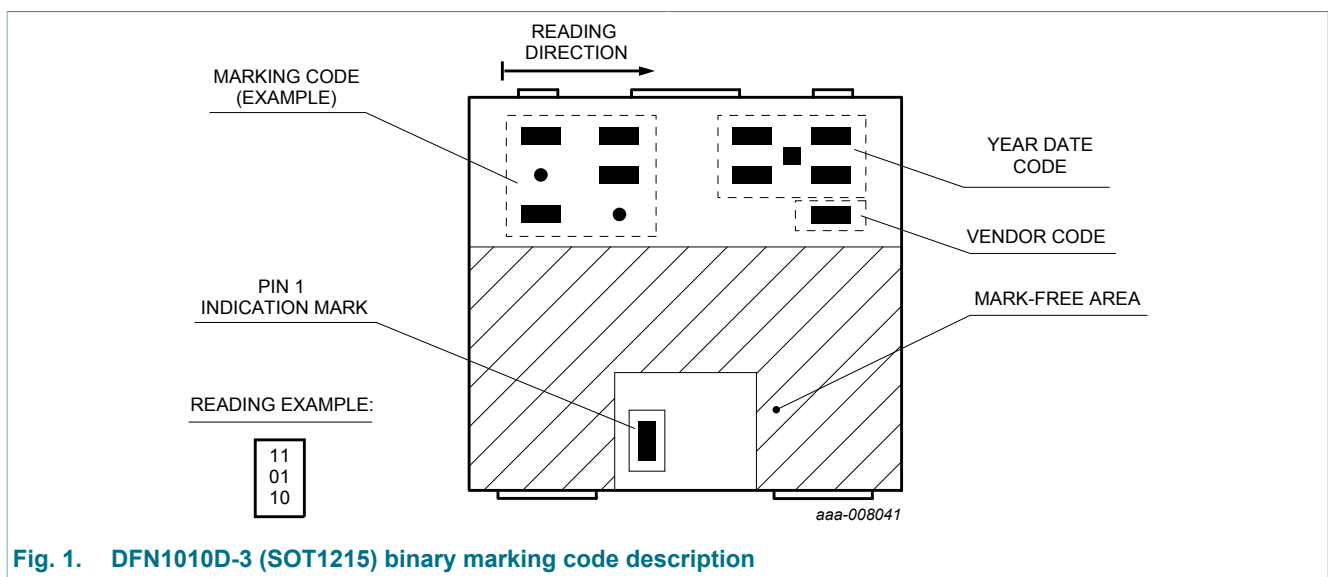
Table 3. Ordering information

Type number	Package		
	Name	Description	Version
PBSS5230QA	DFN1010D-3	plastic thermal enhanced ultra thin small outline package; no leads; 3 terminals	SOT1215

## 7. Marking

Table 4. Marking codes

Type number	Marking code
PBSS5230QA	00 00 10



## 8. Limiting values

**Table 5. Limiting values**

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
$V_{CBO}$	collector-base voltage	open emitter		-	-30	V
$V_{CEO}$	collector-emitter voltage	open base		-	-30	V
$V_{EBO}$	emitter-base voltage	open collector		-	-7	V
$I_C$	collector current			-	-2	A
$I_{CM}$	peak collector current	$t_p \leq 1$ ms; pulsed		-	-3	A
$I_B$	base current			-	-0.3	A
$I_{BM}$	peak base current	$t_p \leq 1$ ms; pulsed		-	-1	A
$P_{tot}$	total power dissipation	$T_{amb} \leq 25$ °C	[1]	-	325	mW
			[2]	-	600	mW
			[3]	-	740	mW
			[4]	-	540	mW
			[5]	-	1000	mW
$T_j$	junction temperature			-	150	°C
$T_{amb}$	ambient temperature			-55	150	°C
$T_{stg}$	storage temperature			-65	150	°C

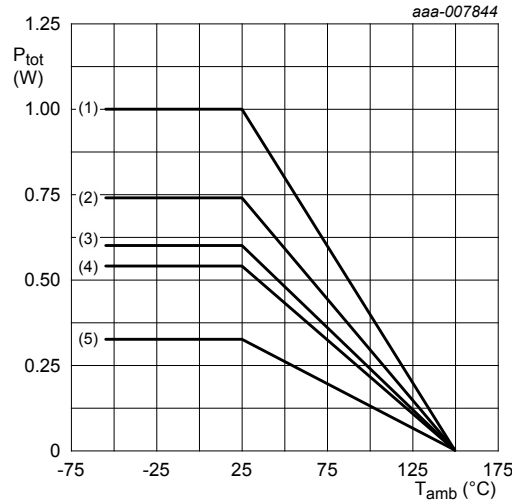
[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated mounting pad for collector 1 cm<sup>2</sup>.

[3] Device mounted on an FR4 PCB, single-sided copper, tin-plated mounting pad for collector 6 cm<sup>2</sup>.

[4] Device mounted on an FR4 PCB, 4-layer copper, tin-plated and standard footprint.

[5] Device mounted on an FR4 PCB, 4-layer copper, tin-plated mounting pad for collector 1 cm<sup>2</sup>.



- (1) FR4 PCB, 4-layer copper, 1 cm<sup>2</sup>
- (2) FR4 PCB, single-sided copper, 6 cm<sup>2</sup>
- (3) FR4 PCB, single-sided copper, 1 cm<sup>2</sup>
- (4) FR4 PCB, 4-layer copper, standard footprint
- (5) FR4 PCB, single-sided copper, standard footprint

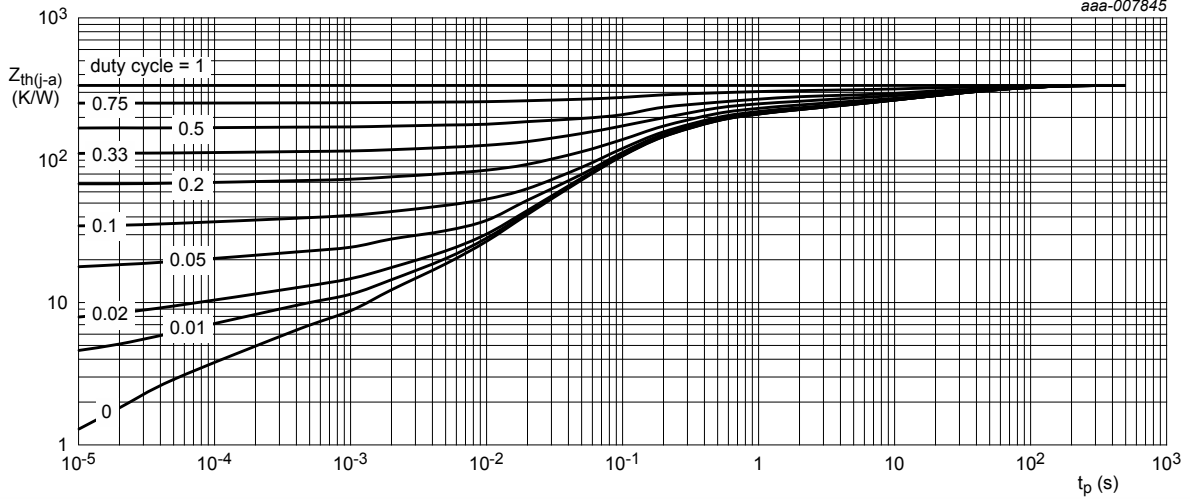
Fig. 2. Power derating curves

## 9. Thermal characteristics

Table 6. Thermal characteristics

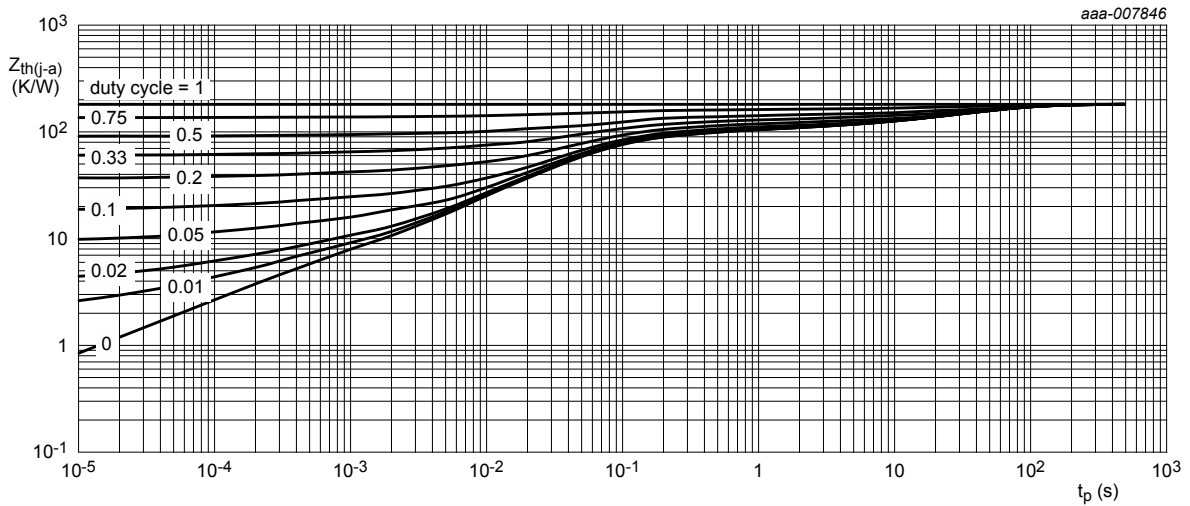
Symbol	Parameter	Conditions		Min	Typ	Max	Unit
R <sub>th(j-a)</sub>	thermal resistance from junction to ambient	in free air	[1]	-	-	385	K/W
			[2]	-	-	209	K/W
			[3]	-	-	169	K/W
			[4]	-	-	232	K/W
			[5]	-	-	125	K/W

- [1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.
- [2] Device mounted on an FR4 PCB, single-sided copper, tin-plated mounting pad for collector 1 cm<sup>2</sup>.
- [3] Device mounted on an FR4 PCB, single-sided copper, tin-plated mounting pad for collector 6 cm<sup>2</sup>.
- [4] Device mounted on an FR4 PCB, 4-layer copper, tin-plated and standard footprint.
- [5] Device mounted on an FR4 PCB, 4-layer copper, tin-plated mounting pad for collector 1 cm<sup>2</sup>.



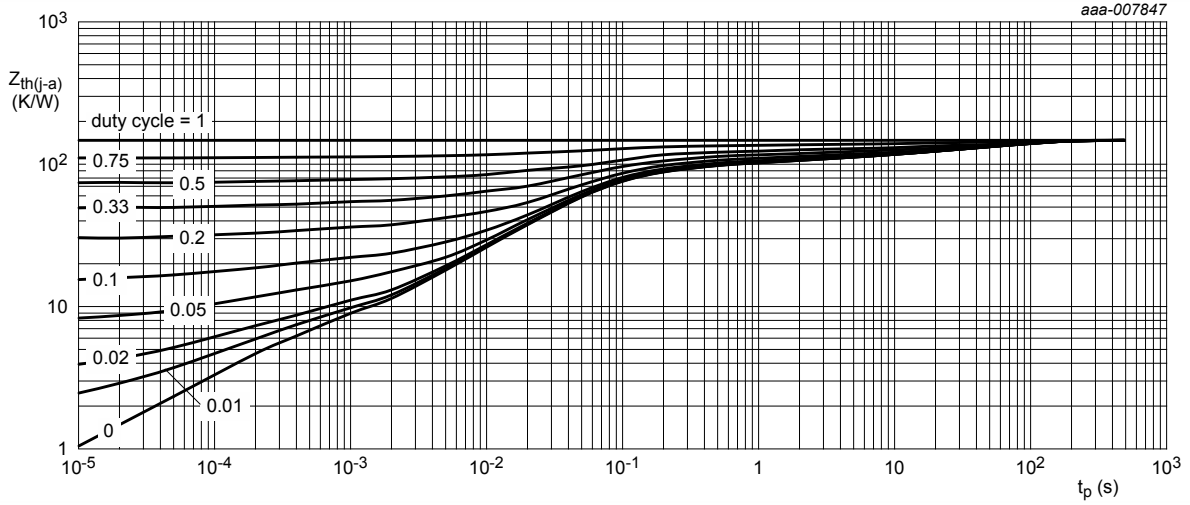
FR4 PCB, single-sided copper, standard footprint

Fig. 3. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values



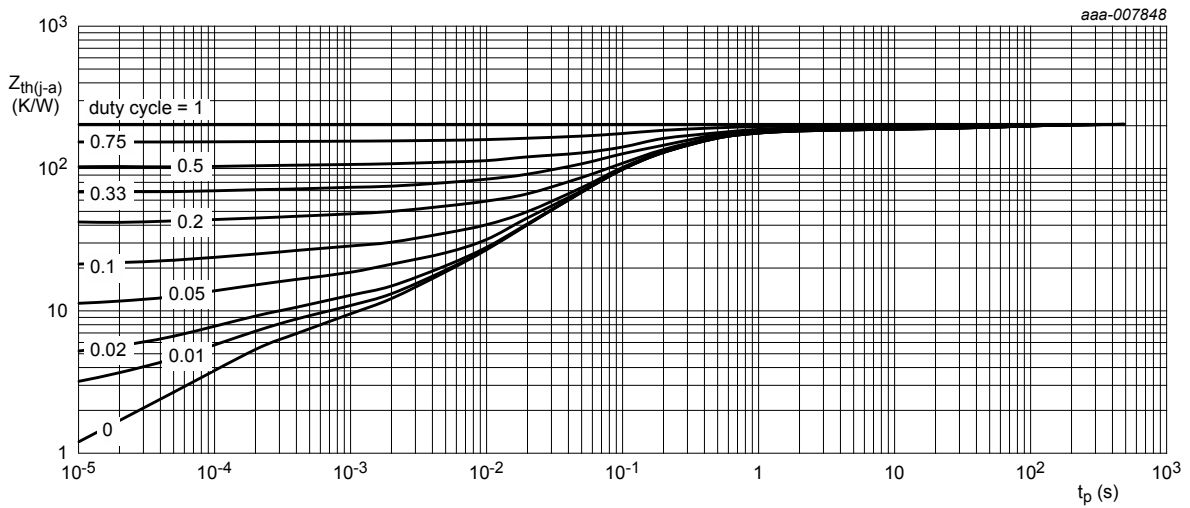
FR4 PCB, single-sided copper, 1 cm<sup>2</sup>

Fig. 4. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values



FR4 PCB, single-sided copper, 6 cm<sup>2</sup>

Fig. 5. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values



FR4 PCB, 4-layer copper, standard footprint

Fig. 6. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

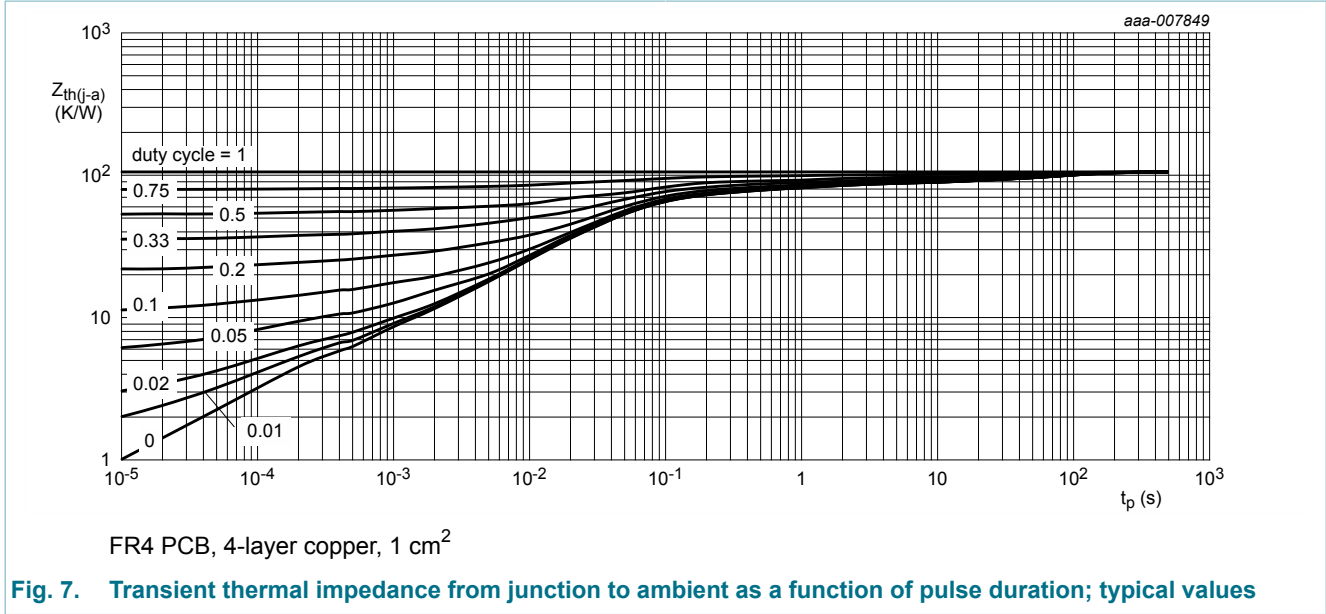


Fig. 7. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

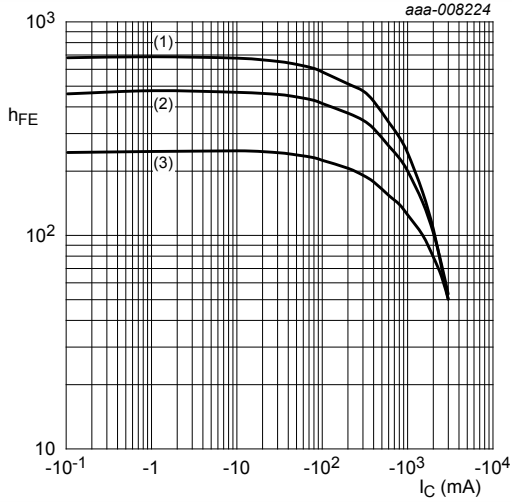
## 10. Characteristics

Table 7. Characteristics

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
I <sub>CBO</sub>	collector-base cut-off current	V <sub>CB</sub> = -24 V; I <sub>E</sub> = 0 A; T <sub>amb</sub> = 25 °C	-	-	-100	nA
		V <sub>CB</sub> = -24 V; I <sub>E</sub> = 0 A; T <sub>j</sub> = 150 °C	-	-	-50	μA
I <sub>CES</sub>	collector-emitter cut-off current	V <sub>CE</sub> = -24 V; V <sub>BE</sub> = 0 V; T <sub>amb</sub> = 25 °C	-	-	-100	nA
I <sub>EBO</sub>	emitter-base cut-off current	V <sub>EB</sub> = -5 V; I <sub>C</sub> = 0 A; T <sub>amb</sub> = 25 °C	-	-	-100	nA
h <sub>FE</sub>	DC current gain	V <sub>CE</sub> = -2 V; I <sub>C</sub> = -100 mA; t <sub>p</sub> ≤ 300 μs; δ ≤ 0.02; T <sub>amb</sub> = 25 °C; pulsed	250	425	-	
		V <sub>CE</sub> = -2 V; I <sub>C</sub> = -500 mA; t <sub>p</sub> ≤ 300 μs; δ ≤ 0.02; T <sub>amb</sub> = 25 °C; pulsed	180	295	-	
		V <sub>CE</sub> = -2 V; I <sub>C</sub> = -1 A; t <sub>p</sub> ≤ 300 μs; δ ≤ 0.02; T <sub>amb</sub> = 25 °C; pulsed	130	200	-	
		V <sub>CE</sub> = -2 V; I <sub>C</sub> = -2 A; t <sub>p</sub> ≤ 300 μs; δ ≤ 0.02; T <sub>amb</sub> = 25 °C; pulsed	60	95	-	
V <sub>CEsat</sub>	collector-emitter saturation voltage	I <sub>C</sub> = -500 mA; I <sub>B</sub> = -50 mA; t <sub>p</sub> ≤ 300 μs; δ ≤ 0.02; T <sub>amb</sub> = 25 °C	-	-70	-100	mV
		I <sub>C</sub> = -1 A; I <sub>B</sub> = -50 mA; t <sub>p</sub> ≤ 300 μs; δ ≤ 0.02; T <sub>amb</sub> = 25 °C	-	-140	-210	mV
		I <sub>C</sub> = -1 A; I <sub>B</sub> = -100 mA; pulsed; t <sub>p</sub> ≤ 300 μs; δ ≤ 0.02; T <sub>amb</sub> = 25 °C	-	-120	-180	mV

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
		$I_C = -2\text{ A}$ ; $I_B = -100\text{ mA}$ ; pulsed; $t_p \leq 300\text{ }\mu\text{s}$ ; $\delta \leq 0.02$ ; $T_{\text{amb}} = 25\text{ }^\circ\text{C}$	-	-275	-410	mV
		$I_C = -2\text{ A}$ ; $I_B = -200\text{ mA}$ ; pulsed; $t_p \leq 300\text{ }\mu\text{s}$ ; $\delta \leq 0.02$ ; $T_{\text{amb}} = 25\text{ }^\circ\text{C}$	-	-220	-330	mV
$R_{\text{CEsat}}$	collector-emitter saturation resistance	$I_C = -1\text{ A}$ ; $I_B = -100\text{ mA}$ ; pulsed; $t_p \leq 300\text{ }\mu\text{s}$ ; $\delta \leq 0.02$ ; $T_{\text{amb}} = 25\text{ }^\circ\text{C}$	-	120	180	m $\Omega$
$V_{\text{BEsat}}$	base-emitter saturation voltage	$I_C = -500\text{ mA}$ ; $I_B = -50\text{ mA}$ ; pulsed; $t_p \leq 300\text{ }\mu\text{s}$ ; $\delta \leq 0.02$ ; $T_{\text{amb}} = 25\text{ }^\circ\text{C}$	-	-0.86	-1	V
		$I_C = -1\text{ A}$ ; $I_B = -50\text{ mA}$ ; pulsed; $t_p \leq 300\text{ }\mu\text{s}$ ; $\delta \leq 0.02$ ; $T_{\text{amb}} = 25\text{ }^\circ\text{C}$	-	-0.89	-1.05	V
		$I_C = -2\text{ A}$ ; $I_B = -100\text{ mA}$ ; pulsed; $t_p \leq 300\text{ }\mu\text{s}$ ; $\delta \leq 0.02$ ; $T_{\text{amb}} = 25\text{ }^\circ\text{C}$	-	-0.98	-1.15	V
		$I_C = -2\text{ A}$ ; $I_B = -200\text{ mA}$ ; pulsed; $t_p \leq 300\text{ }\mu\text{s}$ ; $\delta \leq 0.02$ ; $T_{\text{amb}} = 25\text{ }^\circ\text{C}$	-	-1.02	-1.2	V
$V_{\text{BEon}}$	base-emitter turn-on voltage	$V_{\text{CE}} = -2\text{ V}$ ; $I_C = -0.5\text{ A}$ ; pulsed; $t_p \leq 300\text{ }\mu\text{s}$ ; $\delta \leq 0.02$ ; $T_{\text{amb}} = 25\text{ }^\circ\text{C}$	-	-0.77	-0.9	V
$t_d$	delay time	$V_{\text{CC}} = -10\text{ V}$ ; $I_C = -0.5\text{ A}$ ; $I_{\text{Bon}} = -25\text{ mA}$ ; $I_{\text{Boff}} = 25\text{ mA}$ ; $T_{\text{amb}} = 25\text{ }^\circ\text{C}$	-	10	-	ns
$t_r$	rise time		-	30	-	ns
$t_{\text{on}}$	turn-on time		-	40	-	ns
$t_s$	storage time		-	270	-	ns
$t_f$	fall time		-	45	-	ns
$t_{\text{off}}$	turn-off time		-	315	-	ns
$f_T$	transition frequency		$V_{\text{CE}} = -10\text{ V}$ ; $I_C = -50\text{ mA}$ ; $f = 100\text{ MHz}$ ; $T_{\text{amb}} = 25\text{ }^\circ\text{C}$	120	170	-
$C_c$	collector capacitance	$V_{\text{CB}} = -10\text{ V}$ ; $I_E = 0\text{ A}$ ; $i_e = 0\text{ A}$ ; $f = 1\text{ MHz}$ ; $T_{\text{amb}} = 25\text{ }^\circ\text{C}$	-	14	16	pF

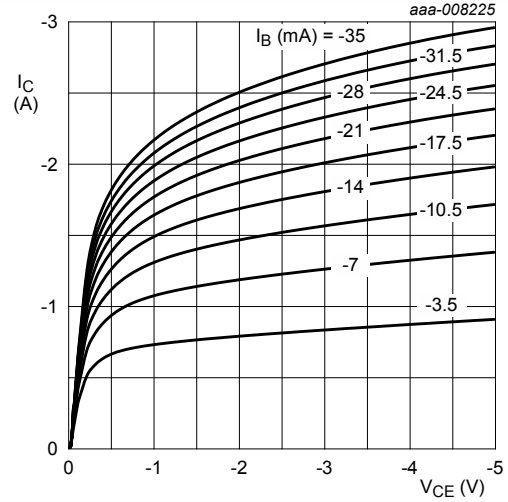




$V_{CE} = -2\text{ V}$

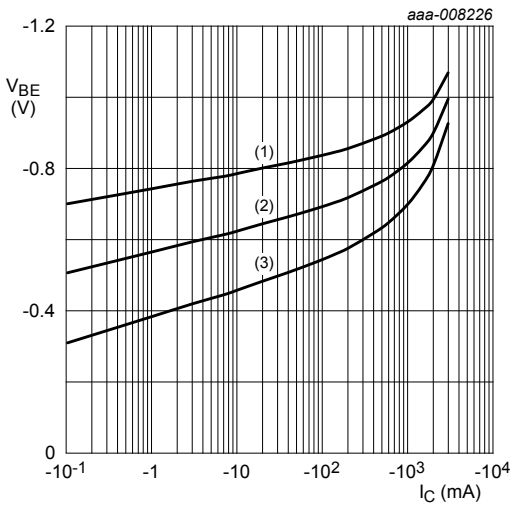
- (1)  $T_{amb} = 100^\circ\text{C}$
- (2)  $T_{amb} = 25^\circ\text{C}$
- (3)  $T_{amb} = -55^\circ\text{C}$

**Fig. 8. DC current gain as a function of collector current; typical values**



$T_{amb} = 25^\circ\text{C}$

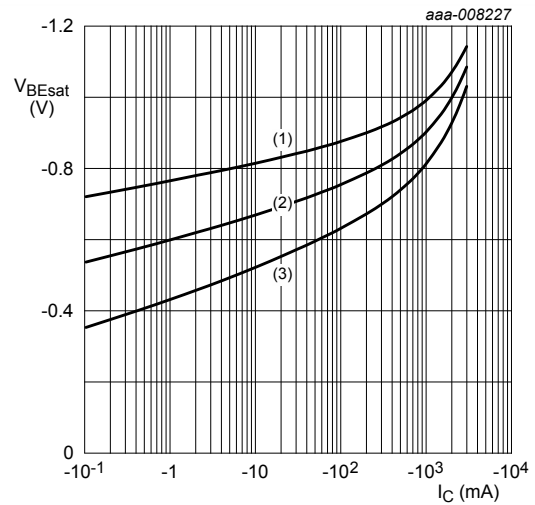
**Fig. 9. Collector current as a function of collector-emitter voltage; typical values**



$V_{CE} = -2\text{ V}$

- (1)  $T_{amb} = -55^\circ\text{C}$
- (2)  $T_{amb} = 25^\circ\text{C}$
- (3)  $T_{amb} = 100^\circ\text{C}$

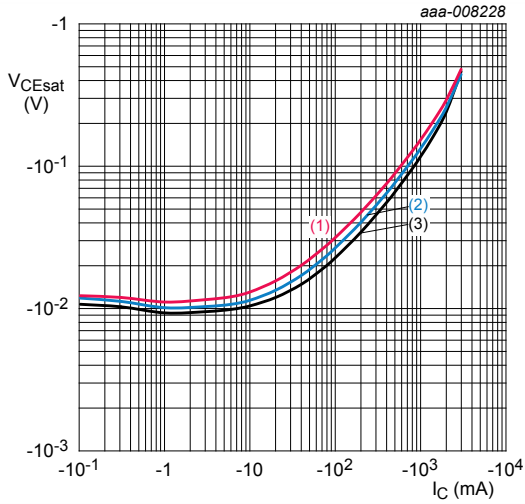
**Fig. 10. Base-emitter voltage as a function of collector current; typical values**



$I_C/I_B = 20$

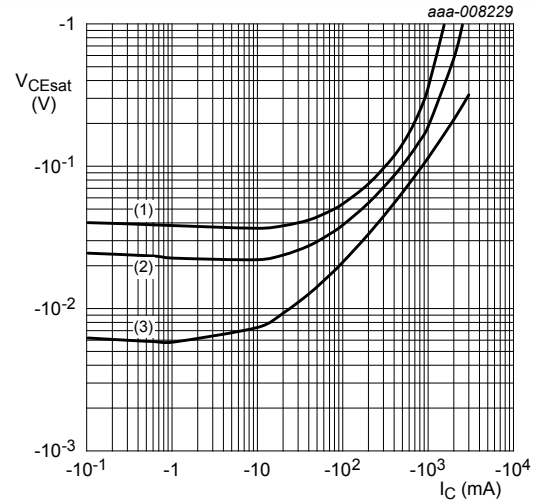
- (1)  $T_{amb} = -55^\circ\text{C}$
- (2)  $T_{amb} = 25^\circ\text{C}$
- (3)  $T_{amb} = 100^\circ\text{C}$

**Fig. 11. Base-emitter saturation voltage as a function of collector current; typical values**



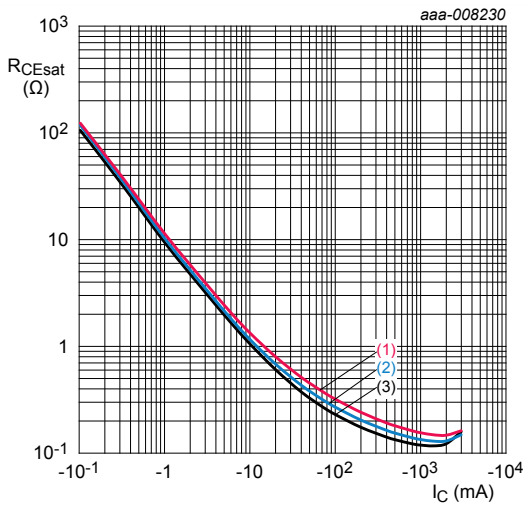
$I_C/I_B = 20$   
 (1)  $T_{amb} = 100^\circ\text{C}$   
 (2)  $T_{amb} = 25^\circ\text{C}$   
 (3)  $T_{amb} = -55^\circ\text{C}$

Fig. 12. Collector-emitter saturation voltage as a function of collector current; typical values



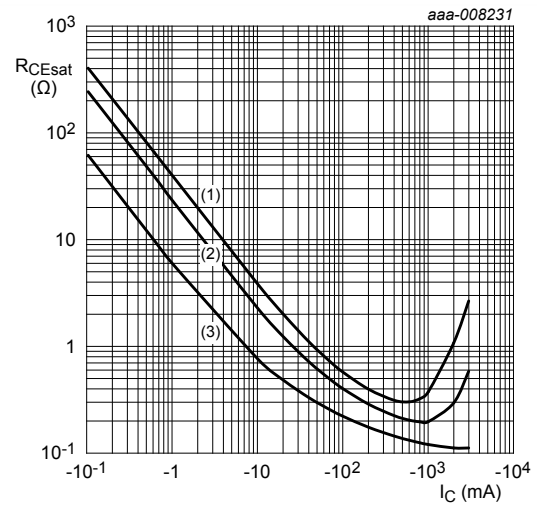
$T_{amb} = 25^\circ\text{C}$   
 (1)  $I_C/I_B = 100$   
 (2)  $I_C/I_B = 50$   
 (3)  $I_C/I_B = 10$

Fig. 13. Collector-emitter saturation voltage as a function of collector current; typical values



$I_C/I_B = 20$   
 (1)  $T_{amb} = 100^\circ\text{C}$   
 (2)  $T_{amb} = 25^\circ\text{C}$   
 (3)  $T_{amb} = -55^\circ\text{C}$

Fig. 14. Collector-emitter saturation resistance as a function of collector current; typical values



$T_{amb} = 25^\circ\text{C}$   
 (1)  $I_C/I_B = 100$   
 (2)  $I_C/I_B = 50$   
 (3)  $I_C/I_B = 10$

Fig. 15. Collector-emitter saturation resistance as a function of collector current; typical values

### 11. Test information

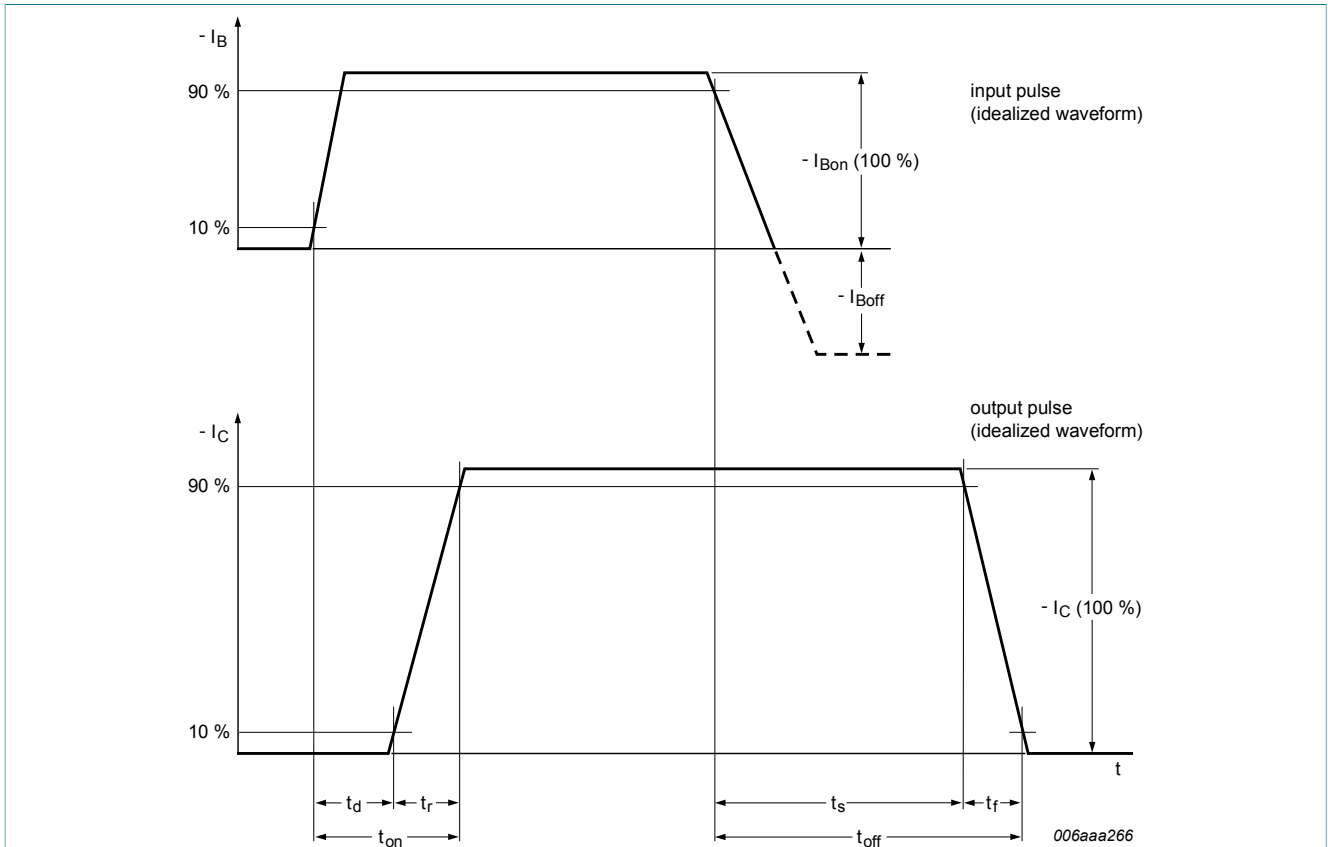


Fig. 16. BISS transistor switching time definition

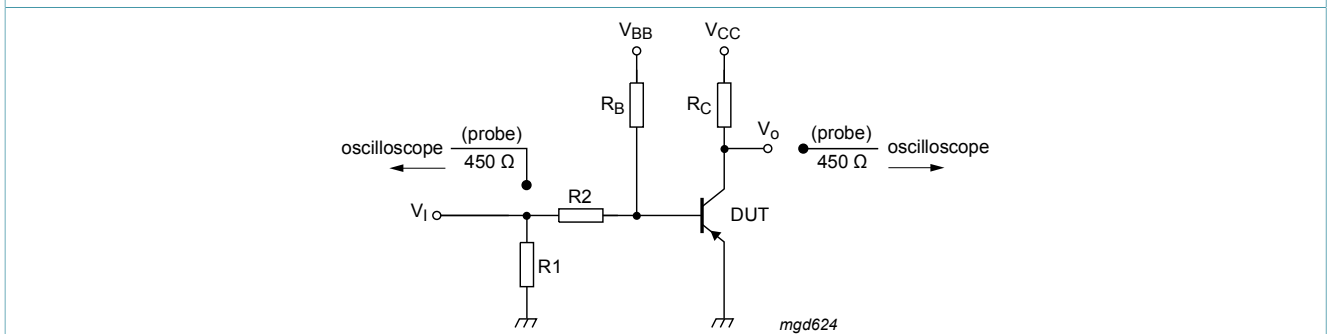


Fig. 17. Test circuit for switching times

#### 11.1 Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard Q101 - *Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.





## 14. Revision history

Table 8. Revision history

Data sheet ID	Release date	Data sheet status	Change notice	Supersedes
PBSS5230QA v.1	20130823	Product data sheet	-	-

## 15. Legal information

### 15.1 Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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- [2] The term 'short data sheet' is explained in section "Definitions".
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Date of release: 23 August 2013

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